## 2SC4672

## NPN EPITAXIAL SILICON TRANSISTOR

# LOW FREQUENCY TRANSISTOR (50V,2A)

#### ■ DESCRIPTION

The UTC 2SC4672 is a low frequency transistor. Excellent DC current gain characteristics.

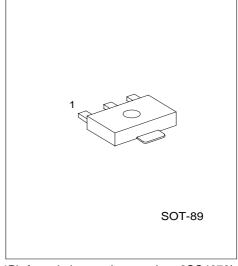
## **■ FEATURES**

\*Low saturation voltage, typically VCE (sat)=0.1V at  $I_{C}$  /  $I_{B}\!\!=\!\!1A$  / 50mA

\*Excellent DC current gain characteristics

#### MARKING





\*Pb-free plating product number: 2SC4672L

#### **■ PIN CONFIGURATION**

PIN NO.	PIN NAME		
1	Emitter		
2	Collector		
3	Base		

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#### ■ ORDERING INFORMATION

Order Number		Package	Dooking	
Normal	Lead free	rackage	Packing	
2SC4672-AB3-R	2SC4672L-AB3-R	SOT-89	Tape Reel	

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### ■ **ABSOLUATE MAXIUM RATINGS** (Ta = $25^{\circ}$ C)

PARAMETER	SYMBOL	RATINGS	UNIT
Collector to Base Voltage	V <sub>CBO</sub>	60	V
Collector to Emitter Voltage	$V_{\sf CEO}$	50	V
Emitter to Base Voltage	V <sub>EBO</sub>	6	V
Collector Current	I <sub>C</sub>	2	Α
Collector Current (Pulse) (Note 1)	I <sub>CP</sub>	5	Α
Collector Dissipation	P <sub>C</sub>	500	mW
Junction Temperature	TJ	+150	°C
Storage Temperature	T <sub>STG</sub>	-40 ~ +150	°C

Note1: Single pulse, P<sub>W</sub>=10ms

#### ■ ELECTRICAL CHARACTERISTICS (Ta= 25°C, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Collector-Base Breakdown Voltage	$BV_CBO$	$I_C = 50 \mu A$	60			V
Collector-Emitter Breakdown Voltage	$BV_CEO$	I <sub>C</sub> =1mA	50			V
Emitter-Base Breakdown Voltage	$BV_{EBO}$	I <sub>E</sub> =50μA	6			V
Collector Cutoff Current	I <sub>CBO</sub>	V <sub>CB</sub> =60V			0.1	μΑ
Emitter Cutoff Current	I <sub>EBO</sub>	V <sub>EB</sub> =5V			0.1	μΑ
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	I <sub>C</sub> /I <sub>B</sub> =1A/50mA (Note1)		0.1	0.35	V
DC Current Transfer Ratio	h <sub>FE</sub>	V <sub>CE</sub> =2V, I <sub>C</sub> =0.5A (Note1)	120		400	
Transition Frequency	$f_{T}$	V <sub>CE</sub> =2V, I <sub>E</sub> =-0.5A, f=100MHz		210		MHz
Output Capacitance	Cob	$V_{CB}$ =10V, $I_E$ =0A,f=1MHz	·	25		pF

Note 1: Measured using pulse current.

## **■ CLASSIFICATION OF hFE**

RANK	Α	В
RANGE	120 ~ 240	200 ~ 400

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